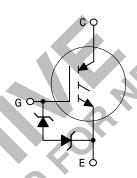
Designer's™ Data Sheet

Insulated Gate Bipolar Transistor

N-Channel Enhancement-Mode Silicon Gate

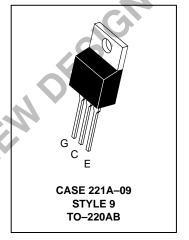
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage–blocking capability. Its new 600 V IGBT technology is specifically suited for applications requiring both a high temperature short circuit capability and a low V_{CE(on)}. It also provides fast switching characteristics and results in efficient operation at high frequencies. This new E–series introduces an energy efficient, ESD protected, and short circuit rugged device.

- Industry Standard TO-220 Package
- High Speed: $E_{off} = 70 \mu J/A$ typical at 125°C
- High Voltage Short Circuit Capability 10 μs minimum at 125°C, 400 V
- Low On-Voltage 2.0 V typical at 5.0 A, 125°C
- Robust High Voltage Termination
- ESD Protection Gate-Emitter Zener Diodes



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IGBT IN TO-220
7.0 A @ 90°C
10 A @ 25°C
600 VOLTS
SHORT CIRCUIT RATED
LOW ON-VOLTAGE



MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	V _{CES}	600	Vdc	
Collector–Gate Voltage (R _{GE} = 1.0 MΩ)	V _{CGR}	600	Vdc	
Gate-Emitter Voltage — Continuous	V_{GE}	±20	Vdc	
Collector Current — Continuous @ T _C = 25°C — Continuous @ T _C = 90°C — Repetitive Pulsed Current (1)	I _{C25} I _{C90} I _{CM}	10 7.0 14	Adc Apk	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	81 0.65	Watts W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C	
Short Circuit Withstand Time (V_{CC} = 400 Vdc, V_{GE} = 15 Vdc, T_J = 125°C, R_G = 20 Ω)	t _{sc}	10	μS	
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R _{θJC} R _{θJA}	1.5 65	°C/W	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C	
Mounting Torque, 6–32 or M3 screw	10	10 lbf•in (1.13 N•m)		

⁽¹⁾ Pulse width is limited by maximum junction temperature. Repetitive rating.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

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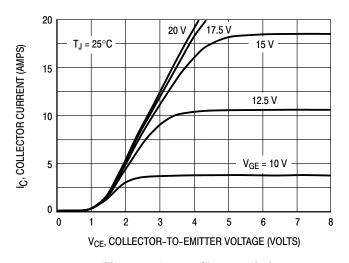


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ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–to–Emitter Breakdown Voltage ($V_{GE}=0$ Vdc, $I_{C}=25~\mu Adc$) Temperature Coefficient (Positive)			600 —	— 870	_	Vdc mV/°C
Emitter-to-Collector Breakdown	V _{(BR)ECS}	15	_	_	Vdc	
Zero Gate Voltage Collector Current $ (V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}) $ $ (V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}) $					10 200	μAdc
Gate-Body Leakage Current (Vo	I _{GES}	_	_	50	μAdc	
ON CHARACTERISTICS (1)						
Collector-to-Emitter On-State V (V_{GE} = 15 Vdc, I_{C} = 2.5 Adc) (V_{GE} = 15 Vdc, I_{C} = 2.5 Adc, T (V_{GE} = 15 Vdc, I_{C} = 5.0 Adc)	V _{CE(on)}		1.6 1.5 2.0	1.9	Vdc	
Gate Threshold Voltage (V _{CE} = V _{GE} , I _C = 1.0 mAdc) Threshold Temperature Coeffic			4.0 —	6.0 10	8.0 —	Vdc mV/°C
Forward Transconductance (V _{CE}	9 _{fe}	<	2.5	_	Mhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{ies}		610	_	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oes}		60	_	
Transfer Capacitance		C _{res}	_	10	_	
SWITCHING CHARACTERISTICS	5(1)					
Turn-On Delay Time		t _{d(on)}	_	22	_	ns
Rise Time	(V _{CC} = 360 Vdc, I _C = 5.0 Adc,	t _r	_	24	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}, \\ R_{G} = 20 \Omega)$	t _{d(off)}	_	64	_	
Fall Time	Energy losses include "tail"	t _f	_	196	_	
Turn-Off Switching Loss		E _{off}	_	0.20	0.34	mJ
Turn-On Delay Time		t _{d(on)}	_	31	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 5.0 \text{ Adc},$	t _r	_	24	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}, \\ R_{G} = 20 \Omega, T_{J} = 125^{\circ}\text{C})$	t _{d(off)}	_	195	_	
Fall Time	Energy losses include "tail"	t _f	_	220	_	1
Turn-Off Switching Loss	7,0	E _{off}	_	0.35	_	mJ
Gate Charge		Q _T	_	27.2	_	nC
	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 5.0 \text{ Adc}, V_{GE} = 15 \text{ Vdc})$	Q ₁	_	7.0	_	1
	vGE = 13 vuc)	Q ₂	_	13.7	_	1
NTERNAL PACKAGE INDUCTAL	ICE					
Internal Emitter Inductance (Measured from the emitter lead 0.25" from package to emitter bond pad)		L _E	_	7.5	_	nH

⁽Measured from the emitter lead 0.25" from package (1) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.





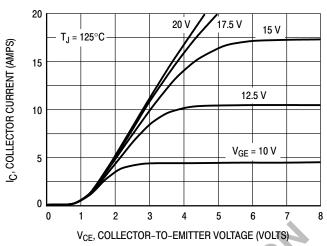


Figure 2. Output Characteristics

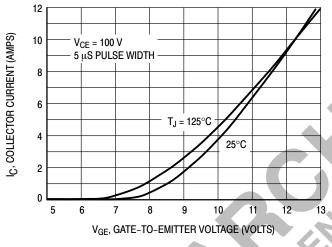


Figure 3. Transfer Characteristics

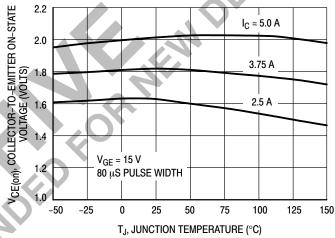


Figure 4. V_{CE} versus Junction Temperature

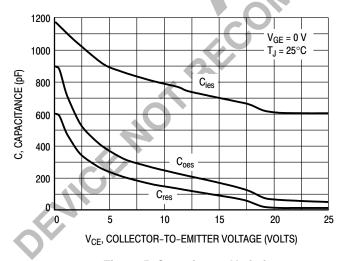


Figure 5. Capacitance Variation

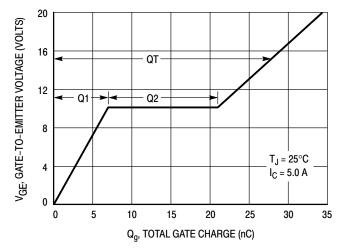


Figure 6. V_{GE} versus Total Charge

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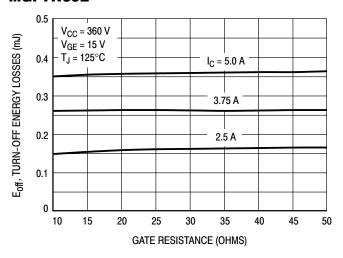


Figure 7. Turn-Off Losses versus Gate Resistance

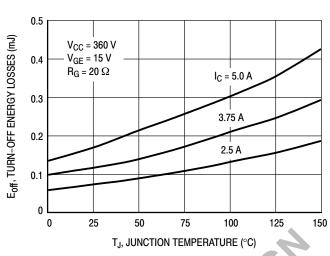
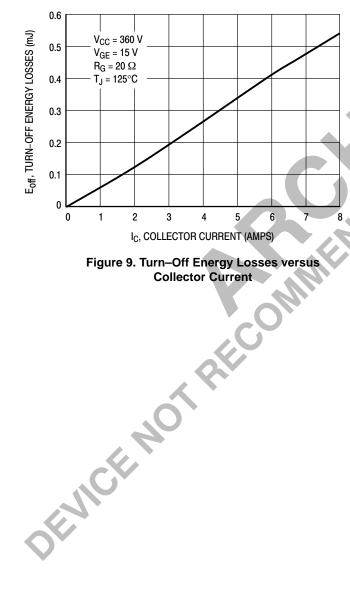


Figure 8. Turn-Off Losses versus Junction **Temperature**



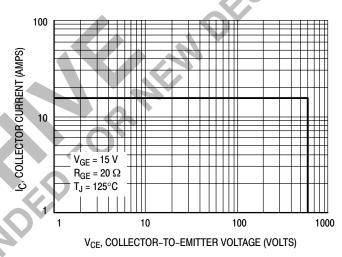
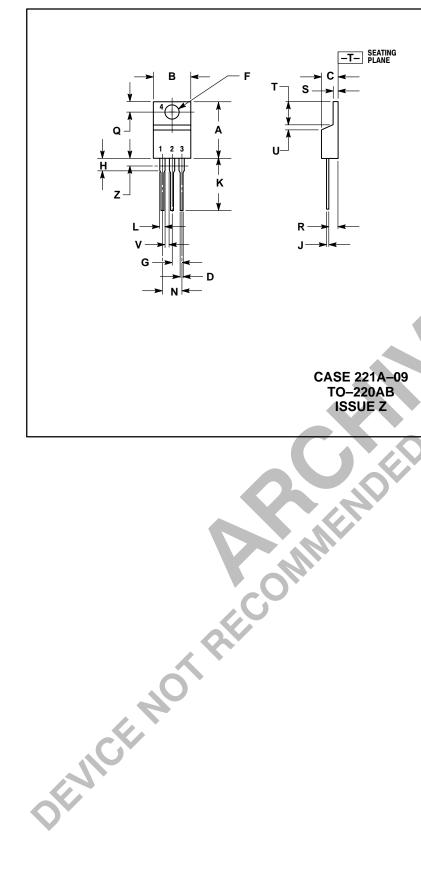


Figure 10. Reverse Biased Safe Operating Area

PACKAGE DIMENSIONS



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- DIMENSIONING AND TOLERANCING PER ANS Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
C	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
7	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
٦	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 9:

PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

CASE 221A-09 TO-220AB



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